


	<h2 style="color: red;">IPD30N03S4L-09</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">IPD30N03S4L-09</a>
	<b>Hersteller / Marke:</b>	<a href="#">International Rectifier (Infineon Technologies)</a>
	<b>Teil der Beschreibung:</b>	IPD30N03S4L-09 Infineon Technologies
<b>Datenblätter:</b>	 <a href="#">IPD30N03S4L-09.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 76050 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">IPD30N03S4L-09</a>
Hersteller	<a href="#">International Rectifier (Infineon Technologies)</a>
Beschreibung	IPD30N03S4L-09 Infineon Technologies
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	76050 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	PG-TO252-3
Verlustleistung (max)	42W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	30A (Tc)
Rds On (Max) @ Id, Vgs	9 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.2V @ 13µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1520pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±16V
Verpackung	Tape & Reel (TR)

IPD30N03S4L-09 ist neu im Original, Suche IPD30N03S4L-09 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPD30N03S4L-09 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPD30N03S4L-09: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>IPD30N03S2L07ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 30V 30A TO252-3</p>	 <p><b>IPD30N03S2L-20</b> INFINEO IPD30N03S2L-20 INFINEO</p>	 <p><b>IPD30N06</b> INFIN IPD30N06 INFIN</p>	 <p><b>IPD30N03S2L-10G</b> Infineon Infineon TO-252</p>
 <p><b>IPD30N03S4L09ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 30V 30A TO252-3</p>	 <p><b>IPD30N03S2L20ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 30V 30A TO252-3</p>	 <p><b>IPD30N03S2L10ATMA1</b> International Rectifier (Infineon Technologies) MOSFET N-CH 30V 30A TO252-3</p>	 <p><b>IPD30N06S2-15</b> International Rectifier (Infineon Technologies) MOSFET N-CH 55V 30A TO252-3</p>

### heiße Teile

Mehr

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|------------------|------------------|------------------|------------------|---------------------|
| ⊗ IPD16CNE8NG    | ↔ IPD170N04NG    | ⇒ IPD180N10N3G   | D IPD200N15N3G   | ⇒ IPD20N031         |
| ⊣ IPD20N03L      | ⊗ IPD20N03LG     | D IPD20N06L      | ⇒ IPD220N06L3G   | ⇒ IPD22N08S2L-50    |
| ⊗ IPD230N06LG    | ⊣ IPD230N06NG    | ⊗ IPD250N06N3G   | ↔ IPD25CN10N     | ⇒ IPD25CN10NG       |
| D IPD25CNE8N     | ⊗ IPD25CNE8NG    | ⊣ IPD25N06S2-40  | ⊗ IPD25N06S4L-30 | ⇒ IPD25N06S4L-30_15 |
| ⇒ IPD26N06S2L-35 | ↔ IPD30N03S2L-07 | ⊗ IPD30N03S2L-08 | ⊣ IPD30N03S2L-10 | ⇒ IPD30N03S2L-20    |
| ↔ IPD30N03S4L-14 | ⇒ IPD30N06       | D IPD30N06S2-15  | ⊗ IPD30N06S2-23  | ⊣ IPD30N06S2L-13    |
| ⊗ IPD30N06S2L-23 | D IPD30N06S3-24  | ⇒ IPD30N06S3L-20 | ↔ IPD30N06S4L-23 | ⇒ IPD30N08S2-22     |
| ⊣ IPD30N08S2L-21 | ⊗ IPD30N10S3L-34 | ↔ IPD320N20N3    | ⇒ IPD320N20N3G   | ⇒ IPD33CN10N        |
| ⊗ IPD33CN10NG    | ⊣ IPD350N06LG    | ⊗ IPD35CN10NG    | D IPD35N10S3L-26 | ⇒ IPD400N06NG       |
| ↔ IPD40N03S4L-08 | ⊗ IPD49CN10NG    | ⊣ IPD50CN10NG    | ⊗ IPD50N03S2-07  | ⇒ IPD50N03S2L-06    |